March 2015



# FGH40N60SFD 600 V, 40 A Field Stop IGBT

### Features

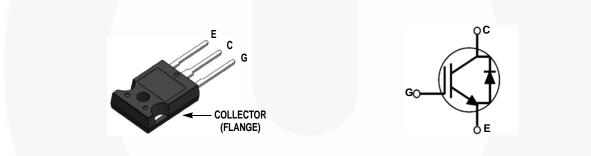
- High Current Capability
- Low Saturation Voltage: V<sub>CE(sat)</sub> = 2.3 V @ I<sub>C</sub> = 40 A
- High Input Impedance
- Fast Switching
- RoHS Compliant

### Applications

 Solar Inverter, UPS, Welder, PFC, Microwave Oven, Telecom, ESS

### **General Description**

Using novel field stop IGBT technology, Fairchild's field stop IGBTs offer the optimum performance for solar inverter, UPS, welder, microwave oven, telecom, ESS and PFC applications where low conduction and switching losses are essential.



### **Absolute Maximum Ratings**

Symbol	Description		Ratings	Unit	
V <sub>CES</sub>	Collector to Emitter Voltage		600	V	
M	Gate to Emitter Voltage		±20	V	
V <sub>GES</sub>	Transient Gate-to-Emitter Voltage		±30	- V	
I <sub>C</sub>	Collector Current	@ T <sub>C</sub> = 25°C	80	A	
ч <b>С</b>	Collector Current	@ T <sub>C</sub> = 100 <sup>o</sup> C	40	А	
I <sub>CM (1)</sub>	Pulsed Collector Current	@ T <sub>C</sub> = 25°C	120	А	
P <sub>D</sub>	Maximum Power Dissipation	@ T <sub>C</sub> = 25°C	290	W	
· U	Maximum Power Dissipation	@ T <sub>C</sub> = 100 <sup>o</sup> C	116	W	
TJ	Operating Junction Temperature		-55 to +150	°C	
T <sub>stg</sub>	Storage Temperature Range		-55 to +150	°C	
Τ <sub>L</sub>	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C	

Notes:

1: Repetitive rating: Pulse width limited by max. junction temperature

### **Thermal Characteristics**

Symbol	Parameter	Тур.	Max.	Unit	
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case	-	0.43	°C/W	
$R_{\theta JC}$ (Diode)	Thermal Resistance, Junction to Case	-	1.45	°C/W	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	-	40	°C/W	

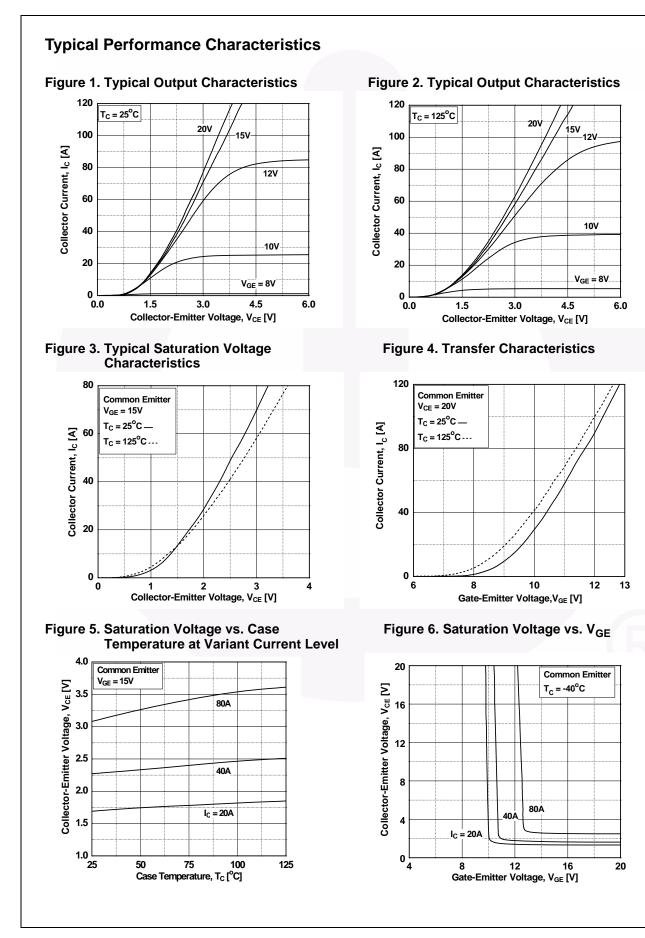
Part Number Top Mark Packa		ge Packing Method		Re	el Size	Tape Width		Quantity		
FGH40N60SFDTU FGH40N60SFD TO-24		7	Tube	N/A		N/A		30		
Electric	al Cha	racteristics o	f the IC	GB.	<b>T</b> $T_{C} = 25^{\circ}C$ unless otherwise	e noted				
Symbol		Parameter			Test Conditions		Min.	Тур.	Max	. Unit
Off Charac	teristics						-			
BV <sub>CES</sub>	Collector	to Emitter Breakdowr	Voltage	Ver	<sub>Ξ</sub> = 0 V, I <sub>C</sub> = 250 μA		600	-	-	V
$\Delta BV_{CES}$ / $\Delta T_J$		ture Coefficient of Bre	0		<sub>E</sub> = 0 V, I <sub>C</sub> = 250 μA		-	0.6	-	V/ºC
ICES		r Cut-Off Current		V <sub>CE</sub> = V <sub>CES</sub> , V <sub>GE</sub> = 0 V		-	_	250	μA	
I <sub>GES</sub>	G-E Lea	kage Current		$V_{CE} = V_{CES}, V_{GE} = 0 V$ $V_{GE} = V_{GES}, V_{CE} = 0 V$		-	-	±400		
510				01						
On Charac	teristics									
V <sub>GE(th)</sub>	G-E Thre	eshold Voltage		-	= 250 $\mu$ A, V <sub>CE</sub> = V <sub>GE</sub>		4.0	5.0	6.5	V
		uration Valtage		= 40 A, V <sub>GE</sub> = 15 V		-	2.3	2.9	V	
V <sub>CE(sat)</sub>	Collector	or to Emitter Saturation Voltage			$I_{C} = 40 \text{ A}, V_{GE} = 15 \text{ V},$ $T_{C} = 125^{\circ}\text{C}$			2.5	-	V
Dynamic C	haracteri	stics								
C <sub>ies</sub>	Input Ca	pacitance					-	2110	-	pF
C <sub>oes</sub>	Output C	apacitance		V <sub>CE</sub> = 30 V <sub>,</sub> V <sub>GE</sub> = 0 V, f = 1 MHz		-	200	-	pF	
C <sub>res</sub>	Reverse	Transfer Capacitance	•				-	60	-	pF
Switching	Character	ristics								
t <sub>d(on)</sub>	Turn-On	Delay Time					-	25	-	ns
t <sub>r</sub>	Rise Tim	e					-	42	-	ns
t <sub>d(off)</sub>	Turn-Off	Delay Time		Vcc	<sub>C</sub> = 400 V, I <sub>C</sub> = 40 A,		-	115	-	ns
t <sub>f</sub>	Fall Time	e		$R_{G}$	$R_G = 10 \Omega$ , $V_{GE} = 15 V$ , Inductive Load, $T_C = 25^{\circ}C$		-	27	54	ns
Eon	Turn-On	Switching Loss		Ind			-	1.13	-	mJ
E <sub>off</sub>	Turn-Off	Switching Loss					-	0.31	-	mJ
E <sub>ts</sub>	Total Sw	itching Loss					-	1.44	-	mJ
t <sub>d(on)</sub>	Turn-On	Delay Time					-	24	-	ns
t <sub>r</sub>	Rise Tim	e					-	43	-	ns
t <sub>d(off)</sub>	Turn-Off	Delay Time		Vcd	<sub>C</sub> = 400 V, I <sub>C</sub> = 40 A,		-	120	-	ns
t <sub>f</sub>	Fall Time	9		$R_{G}$	$R_{G} = 10 \ \Omega$ , $V_{GE} = 15 \ V$ ,		-	30	-	ns
E <sub>on</sub>	Turn-On	Switching Loss		Ind	uctive Load, T <sub>C</sub> = 125 <sup>o</sup> C	,	-	1.14	-	mJ
E <sub>off</sub>	Turn-Off	Switching Loss		1			-	0.48	-	mJ
E <sub>ts</sub>	Total Sw	itching Loss		Ī			-	1.62	-	mJ
Qg	Total Gat	te Charge					-	120	-	nC
Q <sub>ge</sub>	Gate to E	Emitter Charge			= 400 V, I <sub>C</sub> = 40 A,		-	14	-	nC
Q <sub>gc</sub>	Coto to (	Collector Charge			V <sub>GE</sub> = 15 V		_	58	-	nC

FGH40N
60SFD —
600 V, 40
) A Field
Stop IGB

Symbol	Parameter	Test Condition	Min.	Тур.	Max	Unit	
V <sub>FM</sub>	Diode Forward Voltage	I <sub>E</sub> = 20 A	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	1.95	2.6	V
* F M		F = 20 /	$T_{\rm C} = 125^{\rm o}{\rm C}$	-	1.85	-	, ,
t	Diode Reverse Recovery Time		$T_{\rm C} = 25^{\rm o}{\rm C}$	-	45	-	ns
۲r		I <sub>F</sub> =20 A, di <sub>F</sub> /dt = 200 A/μs	$T_{\rm C} = 125^{\rm o}{\rm C}$	-	140	-	
Q <sub>rr</sub>	Diode Reverse Recovery Charge	$r_{\rm F} = 20 \text{ A}, \ \text{ar}_{\rm F}/\text{at} = 200 \text{ A}/\mu\text{s}$	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	75	-	nC
	Diodo Reference Receivery enarge		$T_{\rm C} = 125^{\rm o}{\rm C}$	-	375	-	

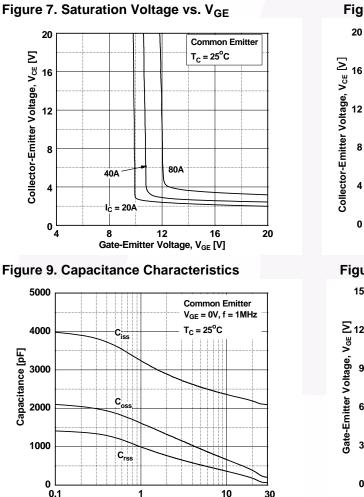
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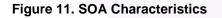
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**Typical Performance Characteristics** 

Collector-Emitter Voltage, V<sub>CE</sub> [V]

1



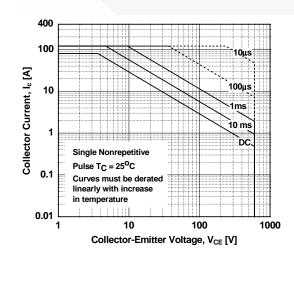
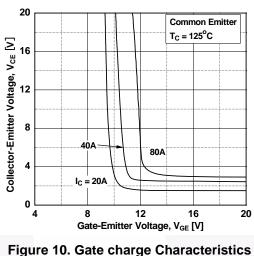
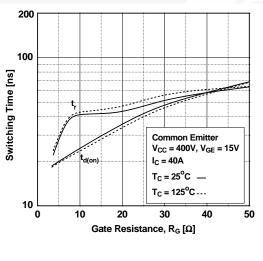


Figure 8. Saturation Voltage vs. V<sub>GE</sub>



Common Emitter  $T_C = 25^{\circ}C$ Gate-Emitter Voltage, V<sub>GE</sub> [V] 8 0 6 71 200V = 100V 300V 0 50 100 150 0 Gate Charge, Q<sub>q</sub> [nC]

Figure 12. Turn-on Characteristics vs. **Gate Resistance** 

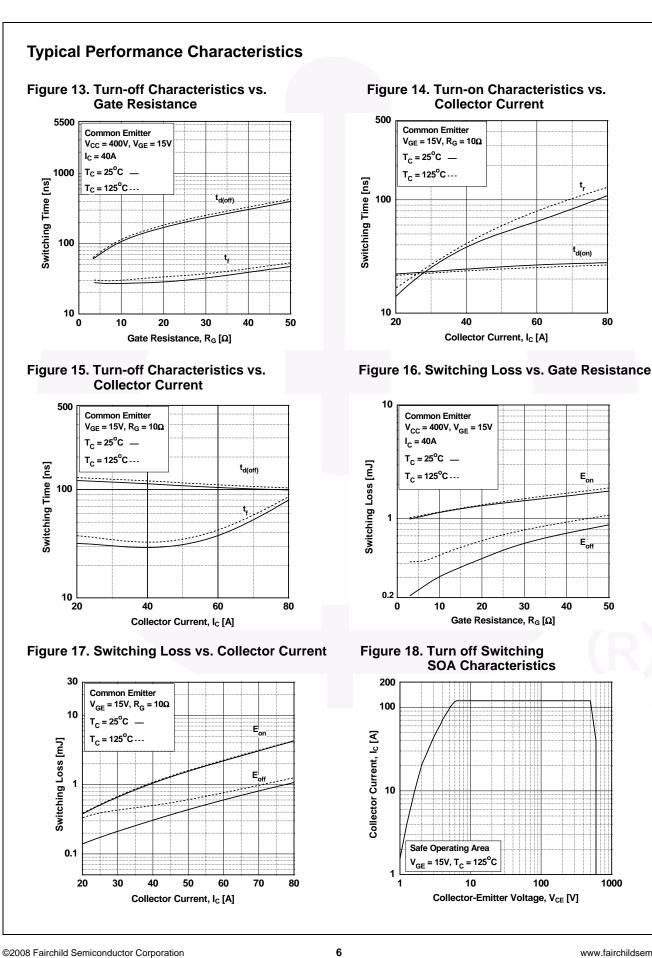


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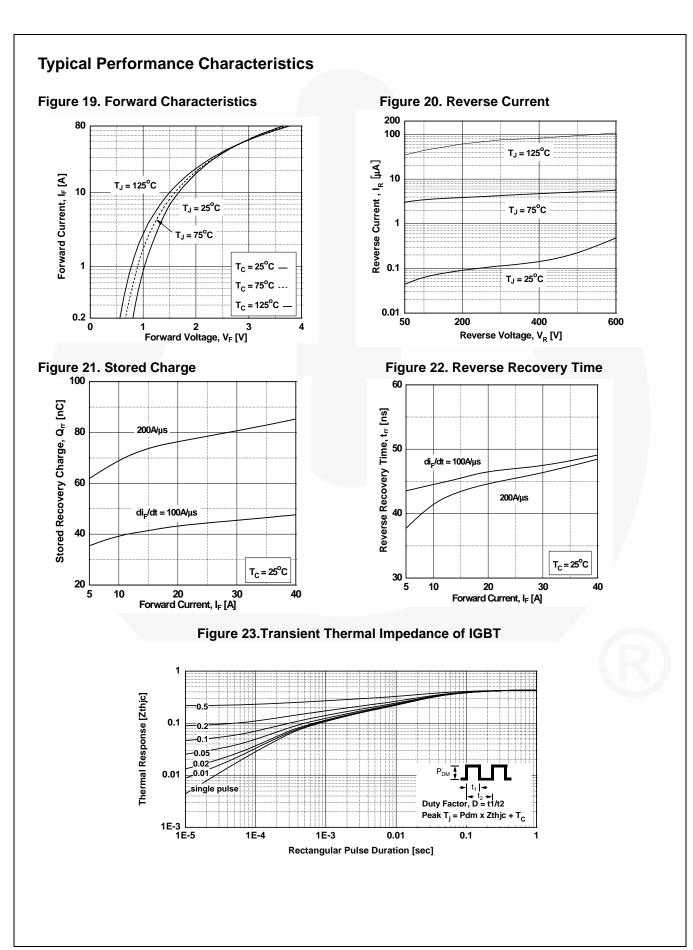
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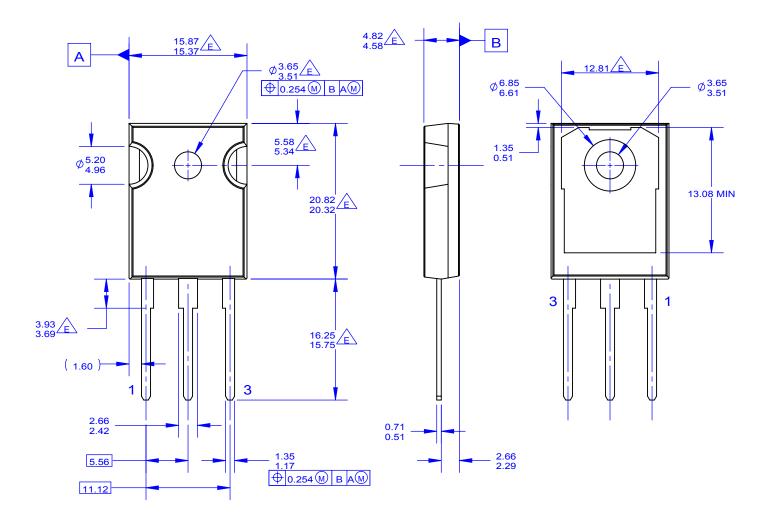
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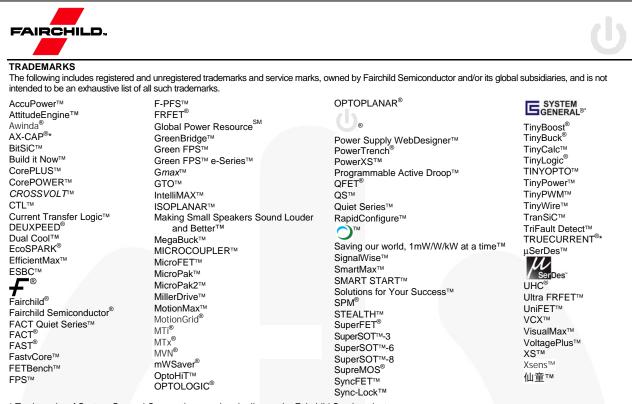




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